NSN 5961-00-412-0908

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-412-0908 **Inclosure Material:** Metal **Overall Length:** 1.000 inches **Overall Diameter:** 1.720 inches **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 300.0 reverse voltage, peak **Current Rating Per Characteristic:** 400.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 190.0 degrees celsius junction **Special Features:** 1 snap-on male terminal **Terminal Type And Quantity:** 1 tab, solder lug Shelf Life: N/a **Unit Of Measure:** Demilitarization: No

Fiig: A110a0